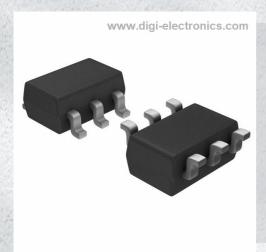


# **HN1B01FU-GR,LXHF Datasheet**



https://www.DiGi-Electronics.com

DiGi Electronics Part Number HN1B01FU-GR,LXHF-DG

Manufacturer Toshiba Semiconductor and Storage

Manufacturer Product Number HN1B01FU-GR,LXHF

Description AUTO AEC-Q PNP + NPN TR VCEO:-50

Detailed Description Bipolar (BJT) Transistor Array 50V 150mA 120MHz, 1

50MHz 200mW Surface Mount US6



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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### **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
HN1B01FU-GR,LXHF	Toshiba Semiconductor and Storage
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
	150mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
50V	300mV @ 10mA, 100mA / 250mV @ 10mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	200 @ 2mA, 6V
Power - Max:	Frequency - Transition:
200mW	120MHz, 150MHz
Operating Temperature:	Grade:
	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
6-TSSOP, SC-88, SOT-363	US6
Base Product Number:	
HN1B01	

### **Environmental & Export classification**

Moisture Sensitivity Level (MSL):	ECCN:
1 (Unlimited)	EAR99
HTSUS:	
8541.21.0075	

Bipolar Transistors Silicon PNP/NPN Epitaxial Type

# HN1B01FU

### 1. Applications

• Low-Frequency Amplifiers

### 2. Q1 Features

- (1) High voltage:  $V_{CEO} = -50 \text{ V}$
- (2) High collector current:  $I_C = -150 \text{ mA (max)}$
- (3) High  $h_{FE}$ :  $h_{FE} = 120$  to 400
- (4) Excellent  $h_{FE}$  linearity:  $h_{FE}$  ( $I_C = -0.1$  mA)/ $h_{FE}$  ( $I_C = -2$  mA) = 0.95 (typ.)

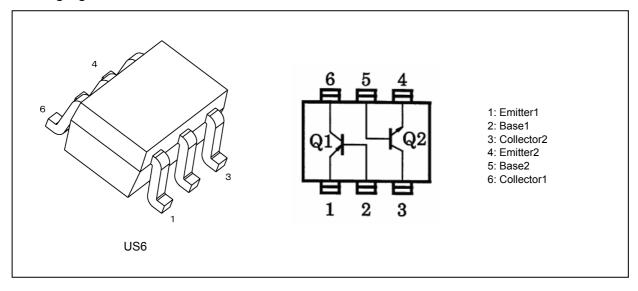
### 3. Q2 Features

- (1) High voltage:  $V_{CEO} = 50 \text{ V}$
- (2) High collector current:  $I_C = 150 \text{ mA (max)}$
- (3) High  $h_{FE}$ :  $h_{FE} = 120$  to 400
- (4) Excellent  $h_{FE}$  linearity:  $h_{FE}$  ( $I_C = 0.1$  mA)/ $h_{FE}$  ( $I_C = 2$  mA) = 0.95 (typ.)

#### 4. Q1, Q2 Common Features

(1) AEC-Q101 qualified (Please see the orderable part number list)

### 5. Packaging and Internal Circuit





### HN1B01FU

### 6. Orderable part number

Orderable part number		AEC-Q101		Note		
HN1B01FU-Y	HN1B01FU-Y,LF	_		General Use		
	HN1B01FU-Y,LXGF	YES	(Note 1)	Unintended Use	(Note 1)	
	HN1B01FU-Y,LXHF	YES		Automotive Use		
HN1B01FU-GR	HN1B01FU-GR,LF	_		General Use		
	HN1B01FU-GR,LXGF	YES	(Note 1)	Unintended Use	(Note 1)	
	HN1B01FU-GR,LXHF	YES		Automotive Use		

Note 1: For more information, please contact our sales or use the inquiry form on our website.

### 7. Q1 Absolute Maximum Ratings (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	I <sub>C</sub>	-150	mA
Base current	I <sub>B</sub>	-30	mA

### 8. Q2 Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25^{\circ}C$ )

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	60	V
Collector-emitter voltage	V <sub>CEO</sub>	50	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	I <sub>C</sub>	150	mA
Base current	I <sub>B</sub>	30	mA

# 9. Q1, Q2 Common Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25°C)

Characteristics			Rating	Unit
Collector power dissipation	(Note 4)	P <sub>C</sub>	200	mW
Junction temperature	(Note 2)	Tj	150	°C
	(Note 3)		125	
Storage temperature	(Note 2)	T <sub>stg</sub>	-55 to 150	°C
	(Note 3)		-55 to 125	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: For devices with the ordering part number ending in LF(T.
- Note 3: For devices with the ordering part number ending in XGF(T, XHF(T.
- Note 4: Device mounted on an FR4 board.(total rating)(25.4 mm × 25.4 mm × 1.6 mm, Cu pad: 0.32 mm<sup>2</sup> × 6)

2022-03-11





### 10. Q1 Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB}$ = -50 V, $I_E$ = 0 mA		_	-0.1	μА
Emitter cut-off current		I <sub>EBO</sub>	$V_{EB}$ = -5 V, $I_C$ = 0 mA		_	-0.1	
DC current gain	(Note)	h <sub>FE</sub>	$V_{CE}$ = -6 V, $I_C$ = -2 mA	120	_	400	_
Collector-emitter saturation voltage		V <sub>CE(sat)</sub>	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$		-0.1	-0.3	V
Transition frequency		f <sub>T</sub>	$V_{CE}$ = -10 V, $I_{C}$ = -1 mA	_	120	_	MHz
Collector output capacitance		C <sub>ob</sub>	$V_{CB}$ = -10 V, $I_E$ = 0 mA, f = 1 MHz		4	_	pF

Note: h<sub>FE</sub> classification Y (Y): 120 to 240, GR (G): 200 to 400

() marking symbol

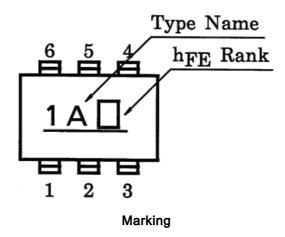
### 11. Q2 Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 60 V, I <sub>E</sub> = 0 mA	_	_	0.1	μА
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB}$ = 5 V, $I_C$ = 0 mA	_	_	0.1	
DC current gain (Note)	h <sub>FE</sub>	$V_{CE} = 6 \text{ V, } I_{C} = 2 \text{ mA}$	120	_	400	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 100 mA, I <sub>B</sub> = 10 mA	_	0.1	0.25	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1 mA	_	150	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0 mA, f = 1 MHz	_	2	_	pF

Note:  $h_{FE}$  classification Y (Y): 120 to 240, GR (G): 200 to 400

() marking symbol

### 12. Marking





COLLECTOR-EMITTER SATURATION VOLTAGE VCE(sat) (V)

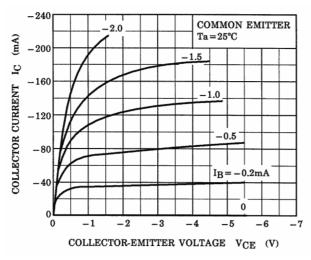
-0.3

-0.1-0.05

0.03

-0.01

### 13. Q1 Characteristics Curves (Note)



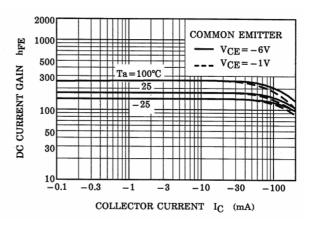
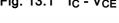
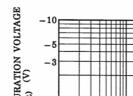
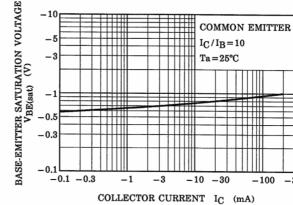


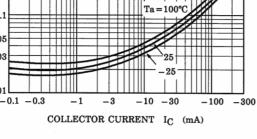
Fig. 13.2 h<sub>FE</sub> - I<sub>C</sub>

Fig. 13.1 I<sub>C</sub> - V<sub>CE</sub>







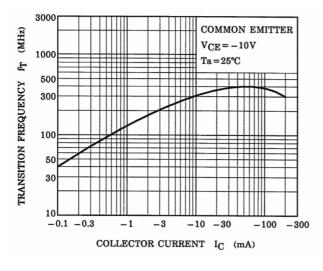


COMMON EMITTER

 $I_C/I_B=10$ 

Fig. 13.3 V<sub>CE(sat)</sub> - I<sub>C</sub>

Fig. 13.4 V<sub>BE(sat)</sub> - I<sub>C</sub>



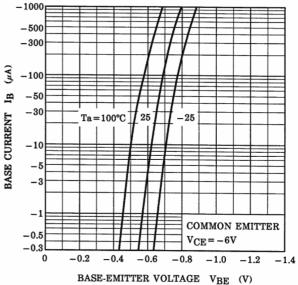


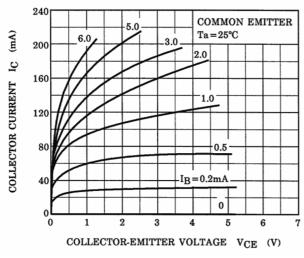
Fig. 13.5 f<sub>T</sub> - I<sub>C</sub>

Fig. 13.6 I<sub>B</sub> - V<sub>BE</sub>

-100 -300

## TOSHIBA

### 14. Q2 Characteristics Curves (Note)



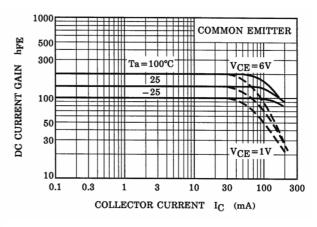


Fig. 14.1 I<sub>C</sub> - V<sub>CE</sub>

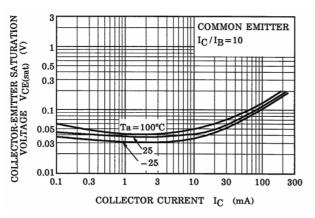


Fig. 14.2 h<sub>FE</sub> - I<sub>C</sub>

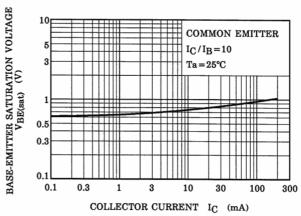


Fig. 14.3 V<sub>CE(sat)</sub> - I<sub>C</sub>

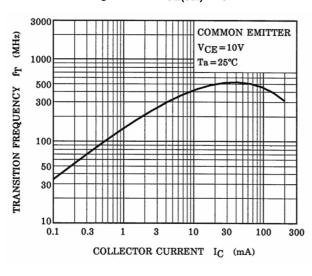


Fig. 14.4 V<sub>BE(sat)</sub> - I<sub>C</sub>

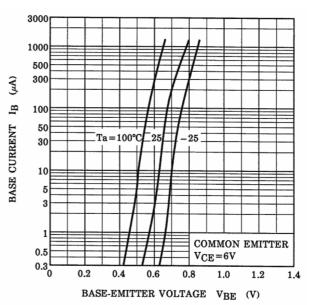


Fig. 14.5 f<sub>T</sub> - I<sub>C</sub>

Fig. 14.6 I<sub>B</sub> - V<sub>BE</sub>



### 15. Q1, Q2 Common Characteristics Curves (Note)

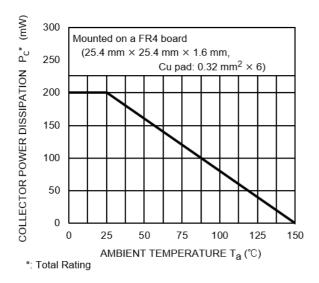


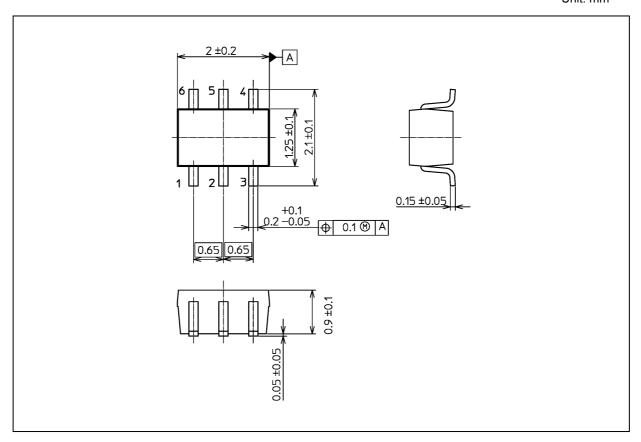
Fig. 15.1 P<sub>C</sub> - T<sub>a</sub> Reference only with T<sub>j</sub> of 150 °C.

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### **Package Dimensions**

Unit: mm



Weight: 6.8 mg (typ.)

	Package Name(s)
TOSHIBA: 1-2T1S	
Nickname: US6	

Rev.3.0



HN1B01FU

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